

Features

- Formerly **FullTec** brand
- Extremely high speed performance
- Blocks high voltages and currents
- Low insertion loss
- Two TBU[™] protectors in one small package
- Very high bandwidth; GHz compatible
- RoHS compliant*, UL Recognized **SN**

Applications

- Mb Ethernet port protection
- Gb Ethernet port protection
- Isolated and floating interfaces

TBU™ P650-U and P850-U Protectors

Transient Blocking Units - TBU™ Devices

Bourns® Model P650-U and P850-U products are high speed, unidirectional protection components, constructed using MOSFET semiconductor technology, designed to protect against faults caused by short circuits, AC power cross, induction and lightning surges.

The TBU™ high speed protector, triggering as a function of the MOSFET, blocks surges and provides an effective barrier behind which sensitive electronics are not exposed to large voltages or currents during surge events. The TBU™ device is provided in a surface mount DFN package and meets industry standard requirements such as RoHS and Pb Free solder reflow profiles.

Agency Approval

UL recognized component File # E315805.

Industry Standards

| | Model | | |
|-----------|-----------------------------------|----------------|--------|
| Telcordia | GR-1089 | Port Type 3, 5 | P650-U |
| | GR-1009 | Port Type 2, 4 | P850-U |
| ITU-T | K.20, K.20E, K.21, K.21E, K.45 | | P850-U |

Absolute Maximum Ratings (T_{amb} = 25 °C)

| Symbol | Parameter | Value | Unit | |
|------------------|---|------------------------------|------------|---|
| V _{imp} | Maximum protection voltage for impulse faults with rise time ≥ 1 μsec | P650-Uxxx-WH P850-Uxxx-WH | 650 850 | V |
| V _{rms} | Maximum protection voltage for continuous V _{rms} faults connected as a series pair (refer to page 3 Test Configuration Diagram) | 300 425 | V | |
| T _{op} | Operating temperature range | -40 to +85 | °C | |
| T _{stg} | Storage temperature range | -65 to +150 | °C | |

Electrical Characteristics (T_{amb} = 25 °C)

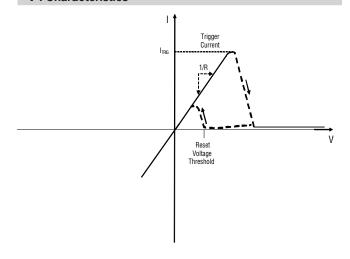
| Symbol | Parameter | | Min. | Тур. | Max. | Unit | |
|----------------------|---|--------------|------|------|------|--------|--|
| | | P650-U180-WH | | | 180 | | |
| 1 | Maximum current through the device that will not cause | P650-U260-WH | | | 260 | mA | |
| lop | current blocking | P850-U180-WH | | | 180 | l IIIA | |
| | | P850-U260-WH | | | 260 | | |
| | | P650-U180-WH | | 220 | | | |
| | Typical current for the device to go from normal operating | P650-U260-WH | | 330 | | mA | |
| l _{trigger} | state to protected state | P850-U180-WH | | 220 | | IIIA | |
| | | P850-U260-WH | | 330 | | | |
| · | | P650-U180-WH | | | 360 | | |
| | Maximum augrent through the device | P650-U260-WH | | | 520 | mA | |
| lout | Maximum current through the device | P850-U180-WH | | | 360 | | |
| | | P850-U260-WH | | | 520 | | |
| В | Coving registering of the TDLIM device | P650-Uxxx-WH | | 6 | 7 | Ω | |
| R _{TBU} | Series resistance of the TBU™ device | P850-Uxxx-WH | | 8 | 9 | | |
| R _{bal} | Line-to line series resistance difference between two TBU™ | device | | | 0.5 | Ω | |
| | Maximum time for the device to go from normal operating | P650-Uxxx-WH | | | 4 | | |
| ^t block | state to protected state | | | ' | μs | | |
| 1 | Current through the triggered TBU™ device with 50 Vdc circu | | 4 | | A | | |
| Iquiescent | voltage | | I | | mA | | |
| ., | Voltage below which the triggered TBU™ device will | P650-Uxxx-WH | | 11 | | .,, | |
| V_{reset} | transition to normal operating state | P850-Uxxx-WH | | 14 | | V | |
| | 1 3 | | | I | I | | |

The P-U Series TBU^TM devices are unidirectional; specifications are valid for input direction only. For the output direction, the TBU^TM device is a resistor.

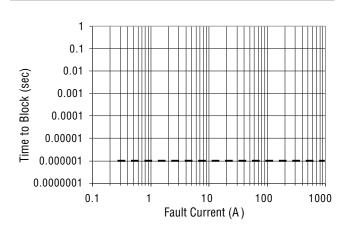
BOURNS®

Typical Performance Characteristics

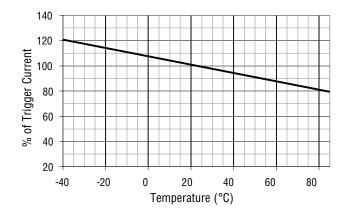
V-I Characteristics



Time to Block vs. Fault Current



Trigger Current vs. Temperature

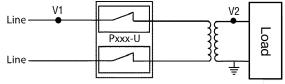


BOURNS

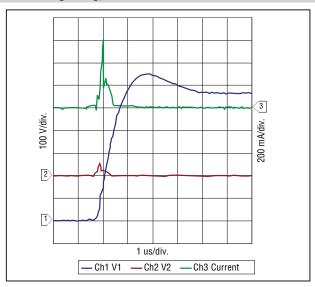
Operational Characteristics

The graphs below demonstrate the operational characteristics of the TBU. For each graph the fault voltage, protected side voltage, and current is presented.

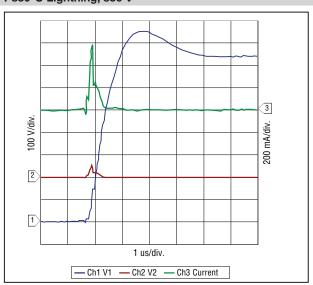
TEST CONFIGURATION DIAGRAM



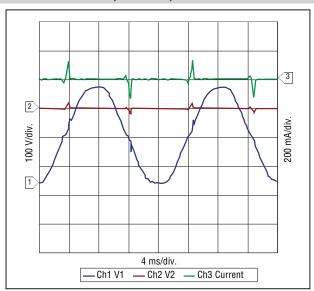
P650-U Lightning, 650 V

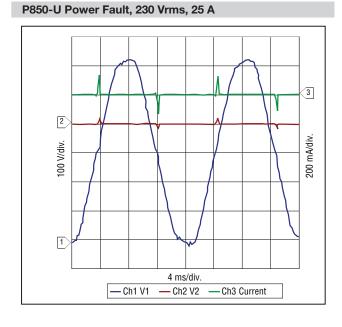


P850-U Lightning, 850 V



P650-U Power Fault, 120 Vrms, 25 A

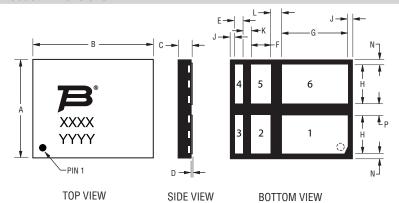




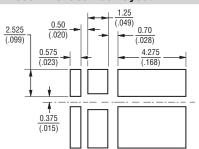
Specifications are subject to change without notice. Customers should verify actual device performance in their specific applications.

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Product Dimensions



Recommended Pad Layout



Pad Designation

| Pad # | Apply |
|-------|-------|
| 1 | ln1 |
| 2 | NC |
| 3 | Out1 |
| 4 | Out2 |
| 5 | NC |
| 6 | In2 |

NC = Solder to PCB; do not make electrical connection, do not connect to ground.

TBU™ devices have matte-tin termination finish. Suggested layout should use non-solder mask define (NSMD). Recommended stencil thickness is 0.10-0.12 mm (.004-.005 in.) with stencil opening size 0.025 mm (.0010 in.) less than the device pad size. As when heat sinking any power device, it is recommended that, wherever possible, extra PCB copper area is allowed. For minimum parasitic capacitance, do not allow any signal, ground or power signals beneath any of the pads of the device.

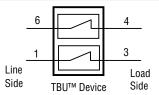
Thermal Resistances

| Symbol | Parameter | Value | Unit |
|----------------------|-----------------------------|-------|------|
| R _{th(j-a)} | Junction to leads (package) | 105 | °C/W |
| | Junction to leads (per TBU) | 202 | °C/W |

| Dim. | Min. | Тур. | Max. | |
|------|-------------|--------------|--------------|--|
| Α | 6.15 | 6.25 | 6.35 | |
| | (.242) | (.246) | (.250) | |
| В | 7.65 | 7.75 | 7.85 | |
| | (.301) | (.305) | (.309) | |
| С | <u>0.80</u> | 0.85 | <u>0.90</u> | |
| | (.031) | (.033) | (.035) | |
| D | 0.000 | <u>0.025</u> | <u>0.050</u> | |
| | (.000) | (.001) | (.002) | |
| E | 0.50 | 0.55 | 0.60 | |
| | (.020) | (.022) | (.024) | |
| F | 1.20 | 1.25 | 1.30 | |
| | (.047) | (.049) | (.051) | |
| G | 4.20 | 4.25 | 4.30 | |
| | (.165) | (.167) | (.169) | |
| Н | 2.45 | 2.50 | <u>2.55</u> | |
| | (.096) | (.098) | (.100) | |
| J | <u>0.20</u> | <u>0.25</u> | <u>0.30</u> | |
| | (.008) | (.010) | (.012) | |
| K | <u>0.45</u> | <u>0.50</u> | <u>0.55</u> | |
| | (.018) | (.020) | (.022) | |
| L | 0.65 | 0.70 | 0.75 | |
| | (.026) | (.028) | (.030) | |
| N | <u>0.20</u> | <u>0.25</u> | <u>0.30</u> | |
| | (.008) | (.010) | (.012) | |
| Р | 0.70 | 0.75 | 0.80 | |
| | (.028) | (.030) | (.031) | |
| Q | 3.20 | 3.25 | 3.30 | |
| | (.126) | (.128) | (.130) | |

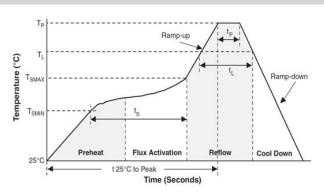
DIMENSIONS: $\frac{MM}{(INCHES)}$

Block Diagram

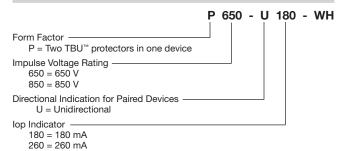


Reflow Profile

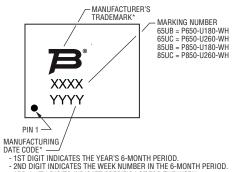
| Pb-Free Assembly |
|------------------|
| 3 °C/sec. max. |
| |
| 150 °C |
| 200 °C |
| 60-180 sec. |
| |
| 217 °C |
| 60-150 sec. |
| 260 °C |
| 20-40 sec. |
| 6 °C/sec. max. |
| 8 min. max. |
| |







Typical Part Marking



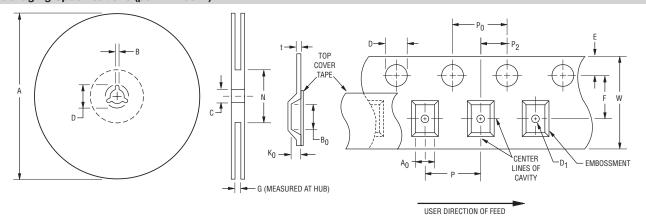
- 3RD & 4TH DIGITS INDICATE SPECIFIC LOT FOR THE WEEK.

6-MONTH PERIOD CODES:

A = JAN-JUN 2009 B = JUL-DEC 2009 C = JAN-JUN 2010 D = JUL-DEC 2010 E = JAN-JUN 2011 F = JUL-DEC 2011

- EXAMPLE: ARBC 15T DIGIT 'A' = JAN-JUN 2009 2ND DIGIT 'R' = WEEK 18; WEEK OF APRIL 27 3RD & 4TH DIGITS 'BC' = LOT SPECIFIC INFORMATION
- *TRANSITION FROM FULTEC TRADEMARK AND LOT CODE TO BOURNS TRADEMARK AND DATE CODE IN 2009.

Packaging Specifications (per EIA468-B)



QUANTITY: 3000 PIECES PER REEL

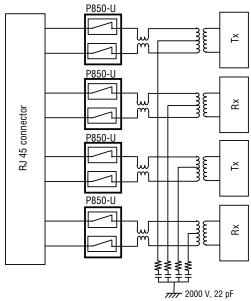
| Device | Α | | В | | С | | D | | G | N |
|----------------|-----------------|--------------------|---------------|---------------|----------------|----------------|----------------|------|----------------|----------------|
| Device | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. | Ref. | Ref. |
| P650-U, P850-U | 326 (12.835) | 330.25 (13.002) | 1.5 (.059) | 2.5 (.098) | 12.8 (.504) | 13.5 (.531) | 20.2 (.795) | - | 16.5 (.650) | 102 (4.016) |

| Device | A ₀ | | В0 | | D | | D ₁ | | E | | F | |
|-------------------|----------------|---------------|----------------|----------------|---------------|----------------|----------------|---------------|----------------|----------------|----------------|----------------|
| Device | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. | Min. | max. |
| P650-U, P850-U | 6.5 (.256) | 6.7 (.264) | 8.0 (.315) | 8.2 (.323) | 1.5 (.059) | 1.6 (.063) | 1.5 (.059) | - | 1.65 (.065) | 1.85 (.073) | 7.4 (.291) | 7.6 (.299) |
| | K ₀ | | Р | | Р | P ₀ | | 2 | t | | W | |
| Device | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. |
| P650-U, P850-U | 1.4 (.055) | 1.6 (.063) | 11.9 (.469) | 12.1 (.476) | 3.9 (.159) | 4.1 (.161) | 1.9 (.075) | 2.1 (.083) | 0.25 (.010) | 0.35 (.014) | 15.7 (.618) | 16.3 (.642) |

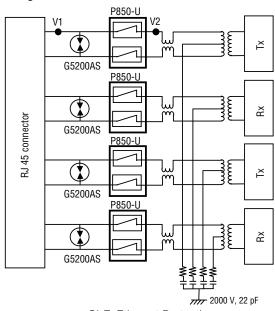
Reference Applications

A cost-effective protection solution utilizes the Bourns® TBU™ protection devices. The diagrams below illustrate common configurations of these components. The graph at the bottom demonstrates the operational characteristics of the circuit.

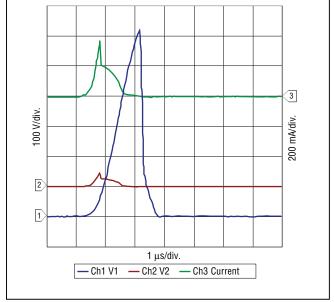
Typical Configuration Diagrams



GbE Ethernet Protection
Up to 1500 V Common-Mode Lightning Protection



GbE Ethernet Protection
Up to 6000 V Common-Mode Lightning Protection



P850-U with G5200AS 4000 V Lightning 10/700 µsec, 150 A



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